# NSN 5961-00-220-6651

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-220-6651

#### Inclosure Material:

Metal

#### **Overall Length:**

Between 0.250 inches and 0.450 inches

# **Overall Diameter:**

0.875 inches

### **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

# **Current Rating Per Characteristic:**

Between 15.00 amperes source cutoff current and 50.00 amperes source cutoff current

# Power Rating Per Characteristic:

300.0 watts small-signal input power, common-collector preset

# Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

81349-mil-s-19500/464 government specification

#### Shelf Life:

N/a

### Unit Of Measure:

---

#### Demilitarization:

No

Fiig:

A110a0